RT1N141X SERIES

(Transistor)

UNIT: mm

Transistor With Resistor For Switching Application Silicon NPN Epitaxial Type

DESCRIPTION

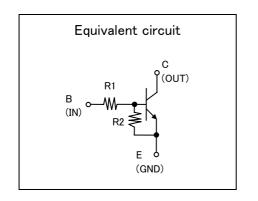
RT1N141X is a one chip transistor with built-in bias resistor, PNP type is RT1P141X.

FEATURE

•Built-in bias resistor (R1=10k Ω ,R2=10k Ω).

APPLICATION

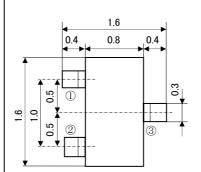
Inverted circuit, switching circuit, interface circuit, driver circuit.



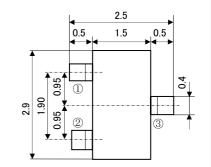
RT1N141S

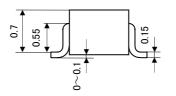
OUTLINE DRAWING

RT1N141C



RT1N141U





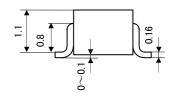
JEITA: — JEDEC: —

Terminal Connector

①:Base

2: Emitter

3: Collector



JEITA: SC-59

JEDEC: Similar to TO-236

Terminal Connector

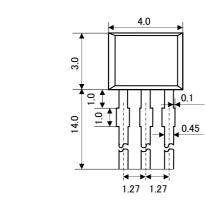
①:Base

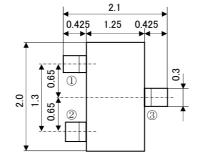
2: Emitter

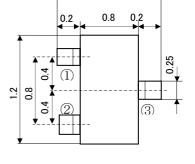
3: Collector

RT1N141M

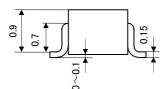
RT1N141T

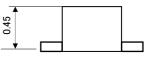












JEITA: — JEDEC:

Terminal Connector

- 1: Emitter
- 2: Collector
- ③:Base

JEITA:SC-70 JEDEC:—

Terminal Connector

- ①:Base
- 2:Emitter
- 3: Collector

JEITA: — JEDEC: —

Terminal Connector

- ①:Base
- 2:Emitter
- 3: Collector

RT1N141X SERIES

(Transistor)

Transistor With Resistor For Switching Application Silicon NPN Epitaxial Type

MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING					UNIT
		RT1N141T	RT1N141U	RT1N141M	RT1N141C	RT1N141S	UNIT
V_{CBO}	Collector to Base voltage	50					٧
V _{EBO}	Emitter to Base voltage	10					V
V _{CEO}	Collector to Emitter voltage	50					V
Ic	Collector current	100					mA
I _{CM}	Peak Collector current	200					mA
P _c	Collector dissipation(Ta=25°C)	125(※)	125	1	50	450	mW
Tj	Junction temperature	+125		+150			°C
Tstg	Storage temperature	−55 ~ +125		−55 ~ +150			°C

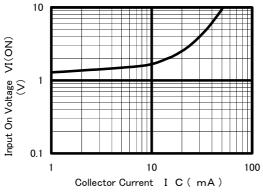
($\mbox{\@monosphice}\xspace$) package mounted on 9mm × 19mm × 1mm glass-epoxy substrate.

ELECTRICAL CHARACTERISTICS (Ta=25°C)

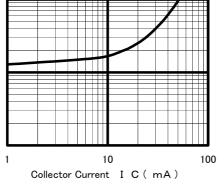
SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
		TEST CONDITION	MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	C to E break down voltage	$I_{C}=100 \mu A, R_{BE}=\infty$	50			٧
I _{CBO}	Collector cut off current	V_{CB} =50V, I $_{E}$ =0			0.1	μΑ
h _{FE}	DC forward current gain	V_{CE} =5V, I $_{C}$ =10mA	50			_
$V_{CE(sat)}$	C to E saturation voltage	$I_{C} = 10$ mA, $I_{B} = 0.5$ mA		0.1	0.3	V
$V_{I(ON)}$	Input on voltage	V_{CE} =0.2V, I $_{C}$ =5mA		1.5	3.0	V
$V_{I(OFF)}$	Input off voltage	V_{CE} =5V, I $_{C}$ =100 μ A	0.8	1.1		٧
R ₁	Input resistance		7.0	10	13	kΩ
R ₂ /R ₁	Resistance ratio		0.9	1.0	1.1	
f _⊤	Gain band width product	$V_{CE}=6V$, $I_{E}=-10mA$		200		MHz

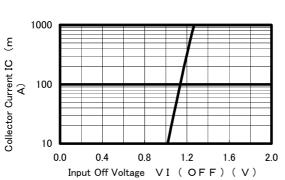
TYPICAL CHARACTERISTICS

Input On Voltage - Collector Current

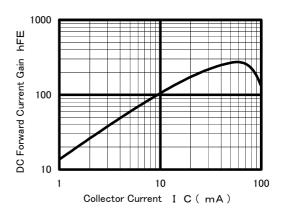


Collector Current - Input Off Voltage





DC Forward Current Gain - Collector Current





Marketing division, Marketing planning department 6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

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